

# TC74VCX125FT, TC74VCX125FK

## Low-Voltage Quad Bus Buffer with 3.6-V Tolerant Inputs and Outputs

The TC74VCX125FT/FK is a high-performance CMOS quad bus buffer which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

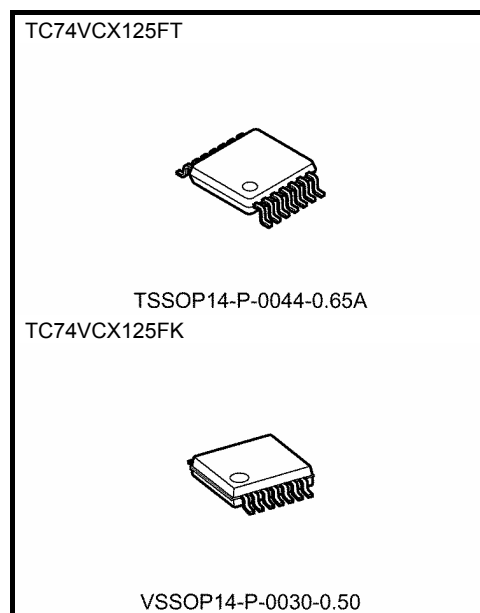
It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

This device requires the 3-state control input  $\overline{OE}$  to be set high to place the output into the high impedance state.

All inputs are equipped with protection circuits against static discharge.

### Features

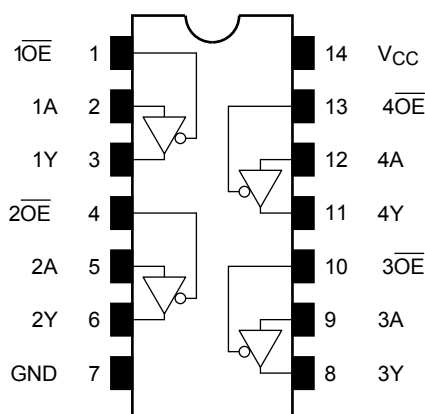
- Low-voltage operation:  $V_{CC} = 1.2 \sim 3.6$  V
- High-speed operation:  $t_{pd} = 2.8$  ns (max) ( $V_{CC} = 3.0 \sim 3.6$  V)  
:  $t_{pd} = 3.4$  ns (max) ( $V_{CC} = 2.3 \sim 2.7$  V)  
:  $t_{pd} = 6.8$  ns (max) ( $V_{CC} = 1.65 \sim 1.95$  V)  
:  $t_{pd} = 13.6$  ns (max) ( $V_{CC} = 1.4 \sim 1.6$  V)  
:  $t_{pd} = 34.0$  ns (max) ( $V_{CC} = 1.2$  V)
- Output current:  $I_{OH}/I_{OL} = \pm 24$  mA (min) ( $V_{CC} = 3.0$  V)  
:  $I_{OH}/I_{OL} = \pm 18$  mA (min) ( $V_{CC} = 2.3$  V)  
:  $I_{OH}/I_{OL} = \pm 6$  mA (min) ( $V_{CC} = 1.65$  V)  
:  $I_{OH}/I_{OL} = \pm 2$  mA (min) ( $V_{CC} = 1.4$  V)
- Latch-up performance:  $-300$  mA
- ESD performance: Machine model  $\geq \pm 200$  V  
Human body model  $\geq \pm 2000$  V
- Package: TSSOP and VSSOP (US)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs.



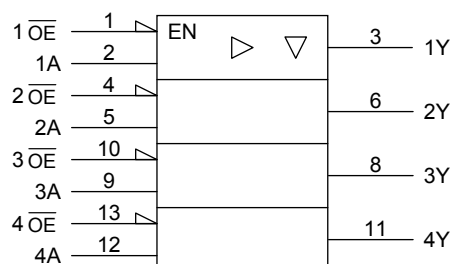
#### Weight

TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

## Pin Assignment (top view)



## IEC Logic Symbol



## Truth Table

Inputs		Outputs
$\overline{OE}$	A	Y
H	X	Z
L	L	L
L	H	H

X: Don't care

Z: High impedance

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5~4.6	V
DC input voltage	$V_{IN}$	-0.5~4.6	V
DC output voltage	$V_{OUT}$	-0.5~4.6 (Note 2)	V
		-0.5~ $V_{CC} + 0.5$ (Note 3)	
Input diode current	$I_{IK}$	-50	mA
Output diode current	$I_{OK}$	±50 (Note 4)	mA
DC output current	$I_{OUT}$	±50	mA
Power dissipation	$P_D$	180	mW
DC $V_{CC}$ /ground current	$I_{CC}/I_{GND}$	±100	mA
Storage temperature	$T_{stg}$	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Off-state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

**Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	1.2~3.6	V
Input voltage	$V_{IN}$	-0.3~3.6	V
Output voltage	$V_{OUT}$	0~3.6 (Note 2)	V
		0~ $V_{CC}$ (Note 3)	
Output current	$I_{OH}/I_{OL}$	$\pm 24$ (Note 4)	mA
		$\pm 18$ (Note 5)	
		$\pm 6$ (Note 6)	
		$\pm 2$ (Note 7)	
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either VCC or GND.

Note 2: OFF state

Note 3: High or low state

Note 4:  $V_{CC} = 3.0\sim 3.6$  V

Note 5:  $V_{CC} = 2.3\sim 2.7$  V

Note 6:  $V_{CC} = 1.65\sim 1.95$  V

Note 7:  $V_{CC} = 1.4\sim 1.6$  V

Note 8:  $V_{IN} = 0.8\sim 2.0$  V,  $V_{CC} = 3.0$  V

## Electrical Characteristics

DC Characteristics ( $T_a = -40$  to  $85^\circ\text{C}$ ,  $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$ )

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.7~3.6	2.0	—	V
	L-level	V <sub>IL</sub>	—		2.7~3.6	—	0.8	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7~3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7~3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 18 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V	2.7~3.6	—	±5.0	μA	
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V	2.7~3.6	—	±10.0	μA	
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V	0	—	10.0	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.7~3.6	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V	2.7~3.6	—	±20.0		
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V	2.7~3.6	—	750		

DC Characteristics ( $T_a = -40$  to  $85^\circ\text{C}$ ,  $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$ )

Characteristics		Symbol	Test Condition			Min	Max	Unit
					V <sub>CC</sub> (V)			
Input voltage	H-level	V <sub>IH</sub>	—		2.3~2.7	1.6	—	V
	L-level	V <sub>IL</sub>	—		2.3~2.7	—	0.7	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3~2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.3	2.0	—	
				I <sub>OH</sub> = -12 mA	2.3	1.8	—	
				I <sub>OH</sub> = -18 mA	2.3	1.7	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3~2.7	—	0.2	
				I <sub>OL</sub> = 12 mA	2.3	—	0.4	
				I <sub>OL</sub> = 18 mA	2.3	—	0.6	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3~2.7	—	±5.0	μA
3-state output off-state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		2.3~2.7	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3~2.7	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		2.3~2.7	—	±20.0	

**DC Characteristics (Ta = -40 to 85°C, 1.65 V ≤ V<sub>CC</sub> < 2.3 V)**

Characteristics		Symbol	Test Condition			Min	Max	Unit	
			V <sub>CC</sub> (V)						
Input voltage	H-level	V <sub>IH</sub>	—		1.65~2.3	0.65 × V <sub>CC</sub>	—	V	
	L-level	V <sub>IL</sub>	—		1.65~2.3	—	0.2 × V <sub>CC</sub>		
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.65~2.3	V <sub>CC</sub> - 0.2	—	V	
				I <sub>OH</sub> = -6 mA	1.65	1.25	—		
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.65~2.3	—	0.2		
				I <sub>OL</sub> = 6 mA	1.65	—	0.3		
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V			1.65~2.3	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V			1.65	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V			0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.65~2.3	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		1.65~2.3	—	±20.0		

**DC Characteristics (Ta = -40 to 85°C, 1.4 V ≤ V<sub>CC</sub> < 1.65 V)**

Characteristics		Symbol	Test Condition			Min	Max	Unit	
			V <sub>CC</sub> (V)						
Input voltage	H-level	V <sub>IH</sub>	—		1.4~1.65	0.65 × V <sub>CC</sub>	—	V	
	L-level	V <sub>IL</sub>	—		1.4~1.65	—	0.05 × V <sub>CC</sub>		
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.4~1.65	V <sub>CC</sub> - 0.2	—	V	
				I <sub>OH</sub> = -2 mA	1.4	1.05	—		
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.4~1.65	—	0.05		
				I <sub>OL</sub> = 2 mA	1.4	—	0.35		
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V			1.4~1.65	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V			1.4~1.65	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V			0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			1.4~1.65	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V			1.4~1.65	—	±20.0	

## DC Characteristics (Ta = -40 to 85°C, 1.2 V ≤ VCC &lt; 1.4 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		1.2~1.4	0.8 × V <sub>CC</sub>	—	V
	L-level	V <sub>IL</sub>	—		1.2~1.4	—	0.05 × V <sub>CC</sub>	V
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.2	V <sub>CC</sub> - 0.1	—	V
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.2	—	0.05	V
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.2	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		1.2	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.2	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		1.2	—	±20.0	

AC Characteristics (Ta = -40 to 85°C, input: t<sub>r</sub> = t<sub>f</sub> = 2.0 ns) (Note 1)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	$t_{pLH}$ $t_{pHL}$	Figure 1, Figure 2	$C_L = 15\text{ pF}, R_L = 2\text{ k}\Omega$	1.2	3.0	34.0	ns
				$1.5 \pm 0.1$	2.0	13.6	
			$C_L = 30\text{ pF}, R_L = 500\text{ }\Omega$	$1.8 \pm 0.15$	1.5	6.8	
				$2.5 \pm 0.2$	0.8	3.4	
				$3.3 \pm 0.3$	0.6	2.8	
3-state output enable time	$t_{pZL}$ $t_{pZH}$	Figure 1, Figure 3	$C_L = 15\text{ pF}, R_L = 2\text{ k}\Omega$	1.2	3.0	41.0	ns
				$1.5 \pm 0.1$	2.0	16.4	
			$C_L = 30\text{ pF}, R_L = 500\text{ }\Omega$	$1.8 \pm 0.15$	1.5	8.2	
				$2.5 \pm 0.2$	0.8	4.1	
				$3.3 \pm 0.3$	0.6	3.5	
3-state output disable time	$t_{pLZ}$ $t_{pHZ}$	Figure 1, Figure 3	$C_L = 15\text{ pF}, R_L = 2\text{ k}\Omega$	1.2	3.0	34.0	ns
				$1.5 \pm 0.1$	2.0	13.6	
			$C_L = 30\text{ pF}, R_L = 500\text{ }\Omega$	$1.8 \pm 0.15$	1.5	6.8	
				$2.5 \pm 0.2$	0.8	3.8	
				$3.3 \pm 0.3$	0.6	3.5	
Output to output skew	$t_{osLH}$ $t_{osHL}$	(Note 2)	$C_L = 15\text{ pF}, R_L = 2\text{ k}\Omega$	1.2	—	1.5	ns
				$1.5 \pm 0.1$	—	1.5	
			$C_L = 30\text{ pF}, R_L = 500\text{ }\Omega$	$1.8 \pm 0.15$	—	0.5	
				$2.5 \pm 0.2$	—	0.5	
				$3.3 \pm 0.3$	—	0.5	

Note 1: For C<sub>L</sub> = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

(t<sub>osLH</sub> = |t<sub>pLHm</sub> - t<sub>pLHn</sub>|, t<sub>osHL</sub> = |t<sub>pHLm</sub> - t<sub>pHLn</sub>|)

**Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF)**

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Quiet output minimum dynamic VOL	VOLP	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	0.8	
Quiet output minimum dynamic VOL	VOLV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	−0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	−0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	−0.8	
Quiet output minimum dynamic VOH	VOHV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	1.5	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	1.9	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	2.2	

Note: Parameter guaranteed by design.

**Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>	—	1.8, 2.5, 3.3	6	pF
Output capacitance	C <sub>O</sub>	—	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note)	1.8, 2.5, 3.3	20	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per bit)}$$

AC Test Circuit

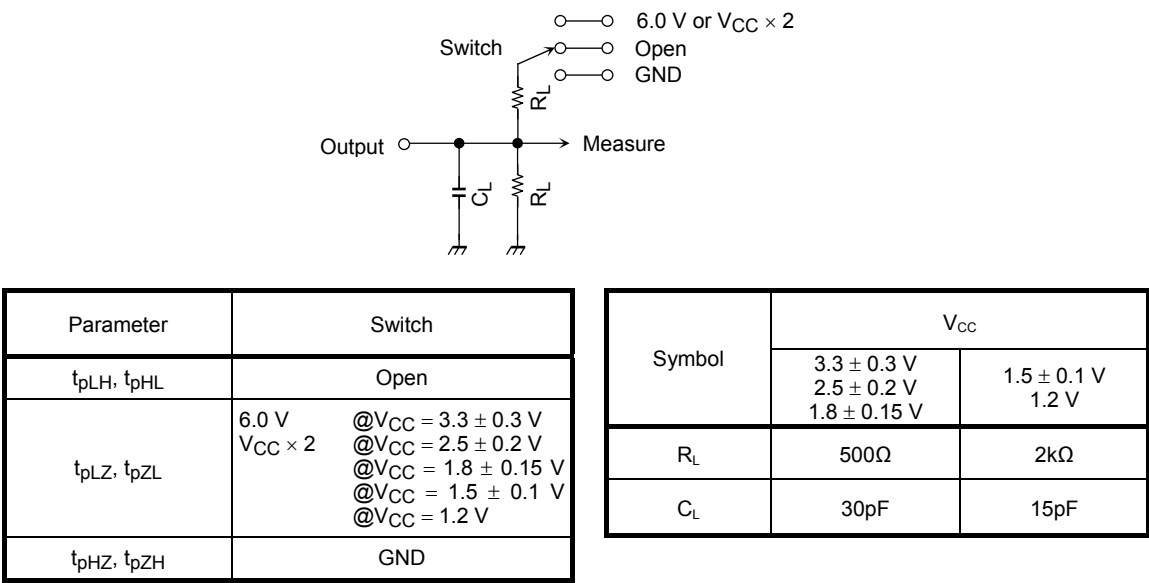


Figure 1

AC Waveform

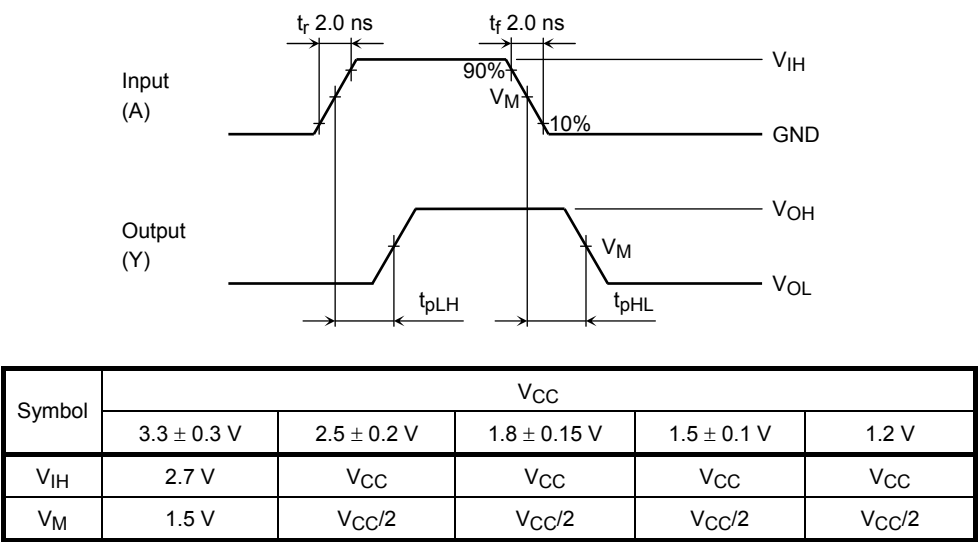
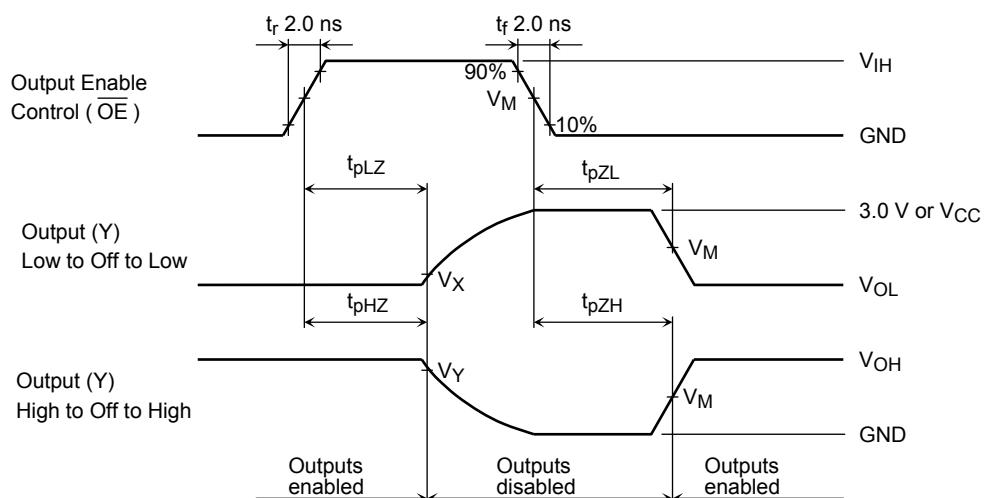


Figure 2  $t_{pLH}, t_{pHL}$



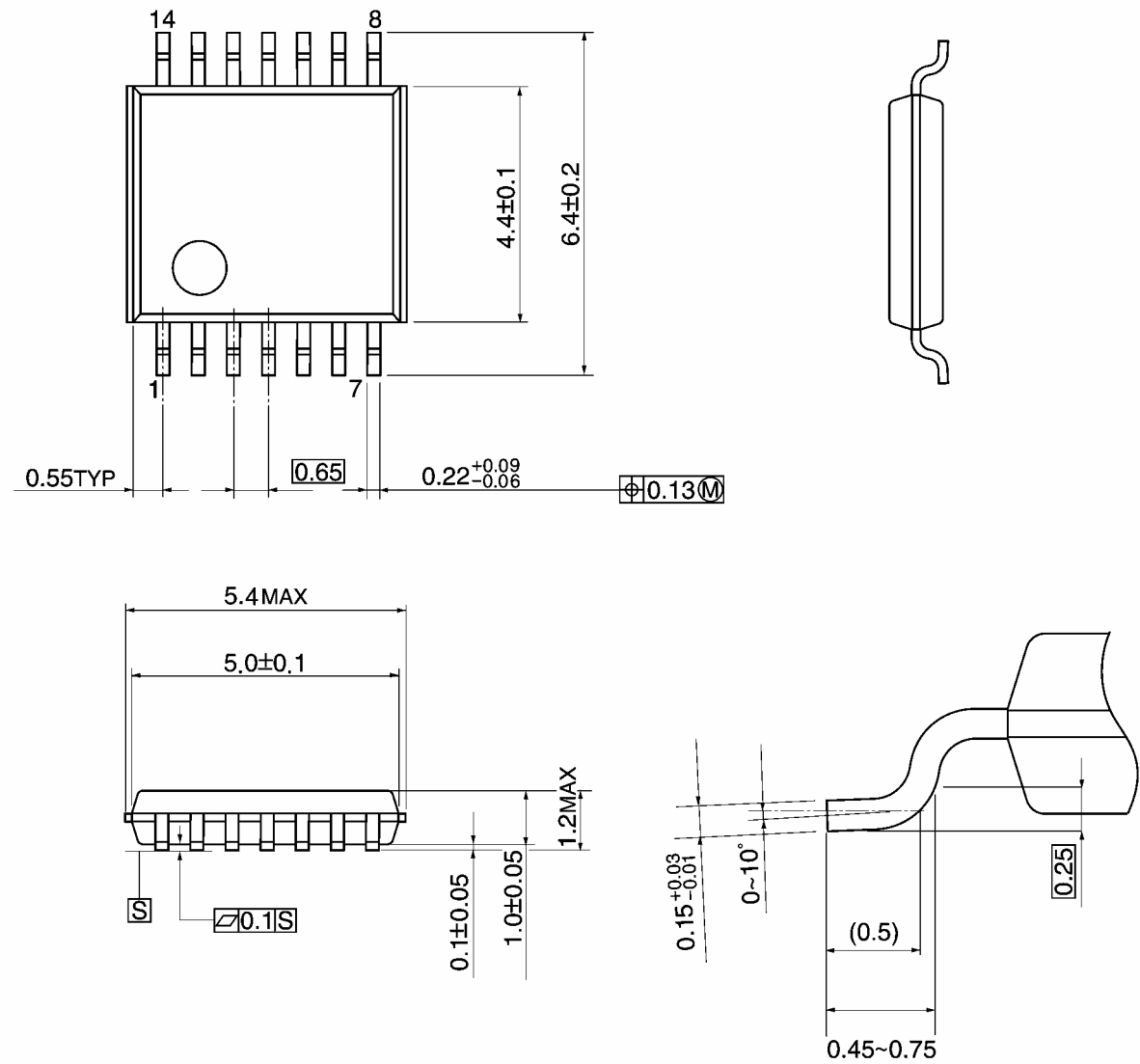

**Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$** 

Symbol	$V_{CC}$				
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	$1.8 \pm 0.15 \text{ V}$	$1.5 \pm 0.1 \text{ V}$	$1.2 \text{ V}$
$V_{IH}$	$2.7 \text{ V}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$
$V_M$	$1.5 \text{ V}$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.1 \text{ V}$	$V_{OL} + 0.1 \text{ V}$
$V_Y$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.1 \text{ V}$	$V_{OH} - 0.1 \text{ V}$

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

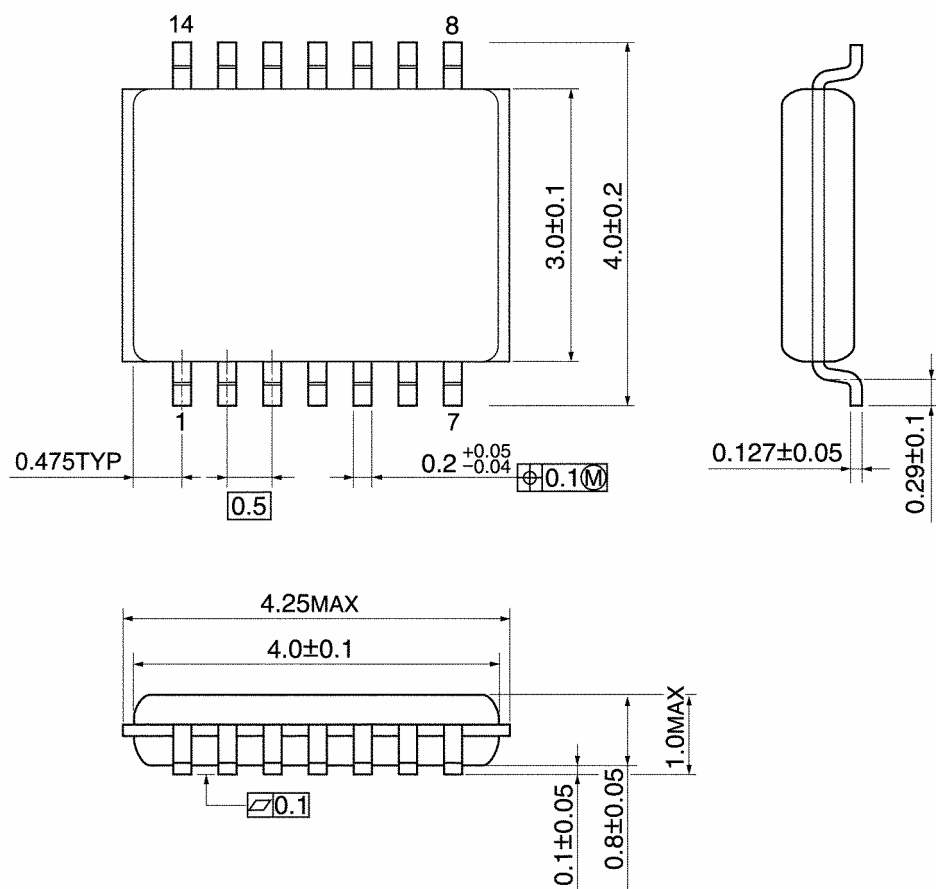


Weight: 0.06 g (typ.)

## Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

**RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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